

## FEATURES

- Power pack
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL Level 1, per J-STD-020, LF MAX peak of 245°C (for TO-263 package)
- Solder bath temperature 275°C maximum, 10s, per JESD22-B106 (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2011/65/EU



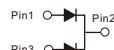
TO-220AB

SR3080SLCT



ITO-220AB

SRF3080SLCT



TO-263

SR3080SLD1



## MECHANICAL DATA

- Case: JEDEC TO-220AB、ITO-220AB、TO-263
- Molding compound meets UL94V-0 flammability rating
- Terminals: Lead solderable per J-STD-002 and JESD22-B102
- Polarity: As marked
- Mounting Torque: 10 in-lbs maximum

## TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

PRIMARY CHARACTERISTICS	
I <sub>F(AV)</sub>	2×15A
V <sub>RRM</sub>	80V
I <sub>FSM</sub>	250A
VF at IF=15.0A,Per leg,125°C	0.49V
I <sub>R</sub>	50 μ A
T <sub>J(MAX)</sub>	150°C
Package	TO-220AB, ITO-220AB, TO-263
Diode variations	Common cathode

## MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified )

Parameter	Symbol	SR3080SLCT, SRF3080SLCT, SR3080SLD1	Unit
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	80	V
Maximum average forward rectified current (see fig.1)	I <sub>F(AV)</sub>	15.0	A
		30.0	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL)	I <sub>FSM</sub>	250	A
Peak repetitive reverse current per diode at t <sub>p</sub> =2 μ s 1KHz	I <sub>RRM</sub>	0.5	A
Operating junction and Storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>	-55 to +150	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t=1 min	V <sub>AC</sub>	1500	V

## RATINGS AND CHARACTERISTIC OF SR3080SLCT,SRF3080SLCT,SR3080SLD1

### ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Test Conditions		Symbol	TYP.	MAX.	Unit
Instantaneous forward voltage	$T_A=25^\circ\text{C}$	$I_F=3.0\text{A}$	$V_F$ <sup>1)</sup>	0.40	—	V
		$I_F=5.0\text{A}$		0.43	—	
		$I_F=15.0\text{A}$		0.54	0.60	
	$T_A=125^\circ\text{C}$	$I_F=3.0\text{A}$		0.28	—	
		$I_F=5.0\text{A}$		0.33	—	
		$I_F=15.0\text{A}$		0.49	—	
Reverse current	$V_R=80\text{V}$	$T_A=25^\circ\text{C}$	$I_R$ <sup>2)</sup>	50	100	$\mu\text{A}$
		$T_A=100^\circ\text{C}$		10	—	mA
		$T_A=125^\circ\text{C}$		40	—	
Typical junction capacitance	4V,1MHz		$C_J$	1400		pF

Notes: 1.Pulse test: 300  $\mu\text{s}$  pulse width,1% duty cycle

2.Pulse test: pulse width  $\leqslant 40\text{ms}$

### THERMAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ Unless otherwise noted)

Parameter	Symbol	SR3080SLCT	SRF3080SLCT	SR3080SLD1	Unit
Typical thermal resistance <sup>3)</sup>	$R_{\theta JC}$	2.5	4.5	2.5	$^\circ\text{C}/\text{W}$

3.Thermal resistance from junction to case

### AVAILABALE PACK INFORMATION

Product code	Pack	Box Size L×W×H(mm)	Quantity(pcs/box)	Carton SizeL×W×H(mm)	Quantity(box/carton)
SR3080SLCT-TO-220AB	P/T	558×148×38	1000	565×225×170	5
SRF3080SLCT-ITO-220AB	P/T	558×148×38	1000	565×225×170	5
SR3080SLD1-TO-263	P/T	558×148×38	1000	565×225×170	5

## RATINGS AND CHARACTERISTIC OF SR3080SLCT, SRF3080SLCT, SR3080SLD1

FIG.1-FORWARD CURRENT DERATING CURVE

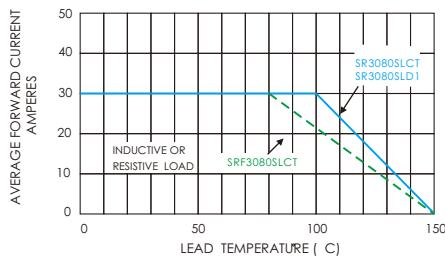


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

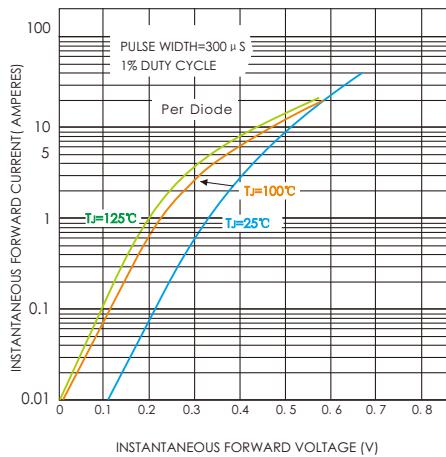


FIG.5-TYPICAL JUNCTION CAPACITANCE

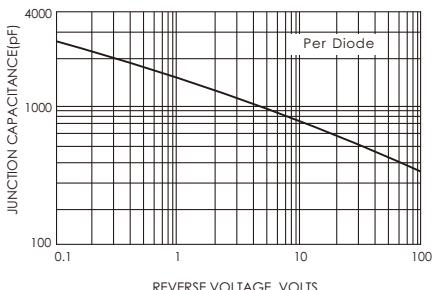


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

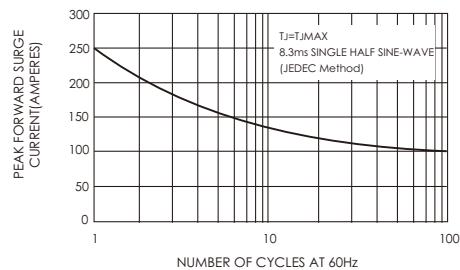
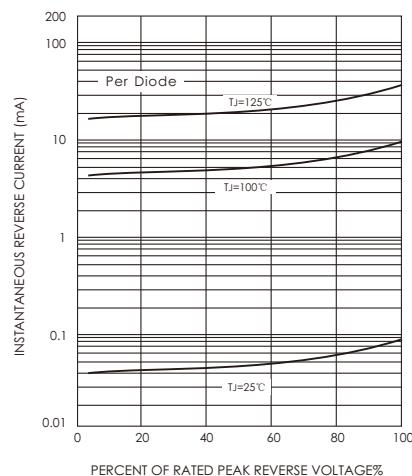
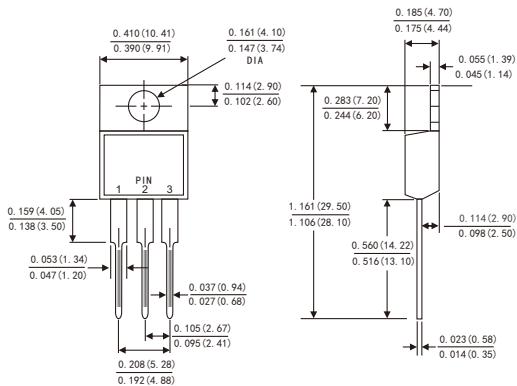


FIG.4-TYPICAL REVERSE CHARACTERISTICS

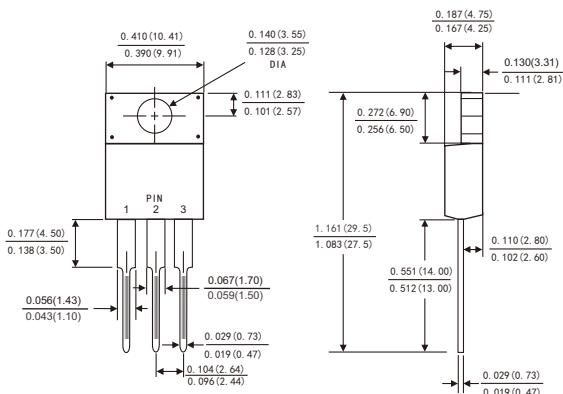


## PACKAGE OUTLINE DIMENSIONS

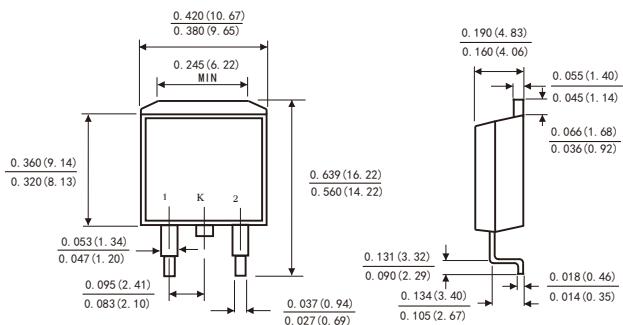
TO-220AB



ITO-220AB

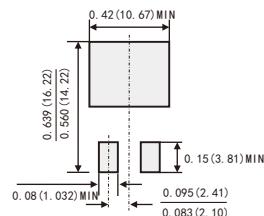


TO-263



## Suggested Pad Layout

(TO-263)



Dimensions in inches and (millimeters)